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FDB28N30TM

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FAIRCHILD SEMICONDUCTOR®

November 2013

FDB28N30

N-Channel UniFET™ MOSFET

300 V, 28 A, 129 mΩ

Features

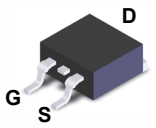
- $R_{DS(on)}$ = 108 mΩ (Typ.) @ V_{GS} = 10 V, I_D = 14 A
- Low Gate Charge (Typ. 39 nC)
- Low C_{rss} (Typ. 35 pF)
- 100% Avalanche Tested
- RoHS Compliant

Applications

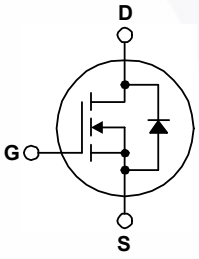
- Uninterruptible Power Supply
- AC-DC Power Supply

Description

UniFET™ MOSFET is Fairchild Semiconductor's high voltage MOSFET family based on planar stripe and DMOS technology. This MOSFET is tailored to reduce on-state resistance, and to provide better switching performance and higher avalanche energy strength. This device family is suitable for switching power converter applications such as power factor correction (PFC), flat panel display (FPD) TV power, ATX and electronic lamp ballasts.



D²-PAK



MOSFET Maximum Ratings T_C = 25°C unless otherwise noted.

Symbol	Parameter		FDB28N30	Unit
V_{DSS}	Drain to Source Voltage		300	V
V_{GSS}	Gate to Source Voltage		±30	V
I_D	Drain Current	- Continuous (T_C = 25°C)	28	A
		- Continuous (T_C = 100°C)	19	
I_{DM}	Drain Current	- Pulsed (Note 1)	112	A
E_{AS}	Single Pulsed Avalanche Energy	(Note 2)	588	mJ
I_{AR}	Avalanche Current	(Note 1)	28	A
E_{AR}	Repetitive Avalanche Energy	(Note 1)	25	mJ
dv/dt	Peak Diode Recovery dv/dt	(Note 3)	4.5	V/ns
P_D	Power Dissipation	(T_C = 25°C)	250	W
		- Derate above 25°C	2.0	W/°C
T_J, T_{STG}	Operating and Storage Temperature Range		-55 to +150	°C
T_L	Maximum Lead Temperature for Soldering, 1/8" from Case for 5 Seconds		300	°C

Thermal Characteristics

Symbol	Parameter	FDB28N30	Unit
$R_{\theta JC}$	Thermal Resistance, Junction to Case, Max.	0.5	°C/W
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient (1 in² Pad of 2-oz Copper), Max.	40	
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient (Minimum Pad of 2-oz Copper), Max.	62.5	

Package Marking and Ordering Information

Part Number	Top Mark	Package	Packing Method	Reel Size	Tape Width	Quantity
FDB28N30	FDB28N30	D^2-PAK	Tape and Reel	330 mm	24 mm	800 units

Electrical Characteristics $T_C = 25^oC$ unless otherwise noted.

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
Off Characteristics						
BV_{DSS}	Drain to Source Breakdown Voltage	I_D = 250 µA, V_{GS} = 0 V, T_J = 25°C	300	-	-	V
ΔBV_{DSS} / ΔT_J	Breakdown Voltage Temperature Coefficient	I_D = 250 µA, Referenced to 25°C	-	0.4	-	V/°C
I_{DSS}	Zero Gate Voltage Drain Current	V_{DS} = 300 V, V_{GS} = 0 V	-	-	1	µA
		V_{DS} = 240 V, T_C = 125°C	-	-	10	
I_{GSS}	Gate to Body Leakage Current	V_{GS} = ±30 V, V_{DS} = 0 V	-	-	±100	nA
On Characteristics						
$V_{GS(th)}$	Gate Threshold Voltage	V_{GS} = V_{DS}, I_D = 250 µA	3.0	-	5.0	V
$R_{DS(on)}$	Static Drain to Source On Resistance	V_{GS} = 10 V, I_D = 14 A	-	0.108	0.129	Ω
g_{FS}	Forward Transconductance	V_{DS} = 40 V, I_D = 14 A	-	24.8	-	S
Dynamic Characteristics						
C_{iss}	Input Capacitance	V_{DS} = 25 V, V_{GS} = 0 V, f = 1 MHz	-	1690	2250	pF
C_{oss}	Output Capacitance		-	305	405	pF
C_{rss}	Reverse Transfer Capacitance		-	35	50	pF
Q_g	Total Gate Charge at 10V	V_{DS} = 240 V, I_D = 28 A, V_{GS} = 10 V (Note 4)	-	39	50	nC
Q_{gs}	Gate to Source Gate Charge		-	12	-	nC
Q_{gd}	Gate to Drain “Miller” Charge		-	17	-	nC
Switching Characteristics						
$t_{d(on)}$	Turn-On Delay Time	V_{DD} = 150 V, I_D = 28 A, V_{GS} = 10 V, R_G = 25 Ω (Note 4)	-	35	80	ns
t_r	Turn-On Rise Time		-	135	280	ns
$t_{d(off)}$	Turn-Off Delay Time		-	79	168	ns
t_f	Turn-Off Fall Time		-	69	148	ns
Drain-Source Diode Characteristics						
I_S	Maximum Continuous Drain to Source Diode Forward Current		-	-	28	A
I_{SM}	Maximum Pulsed Drain to Source Diode Forward Current		-	-	112	A
V_{SD}	Drain to Source Diode Forward Voltage	V_{GS} = 0 V, I_{SD} = 28 A	-	-	1.4	V
t_{rr}	Reverse Recovery Time	V_{GS} = 0 V, I_{SD} = 28 A, dI_F/dt = 100 A/µs	-	279	-	ns
Q_{rr}	Reverse Recovery Charge		-	2.7	-	µC

Notes:

1. Repetitive rating: pulse-width limited by maximum junction temperature.
2. L = 1.5 mH, I_{AS} = 28 A, V_{DD} = 50 V, R_G = 25 Ω, starting T_J = 25°C.
3. I_{SD} ≤ 28 A, di/dt ≤ 200 A/µs, V_{DD} ≤ BV_{DSS}, starting T_J = 25°C.
4. Essentially independent of operating temperature typical characteristics.

Typical Performance Characteristics

Figure 1. On-Region Characteristics

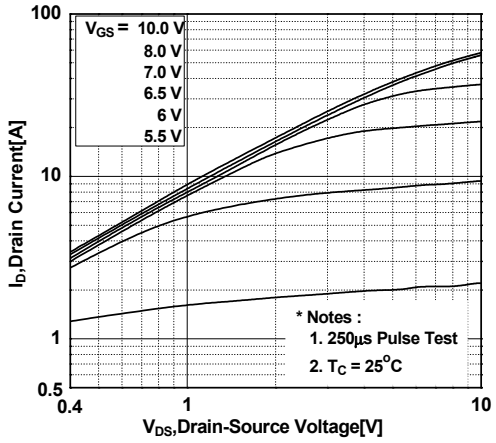


Figure 2. Transfer Characteristics

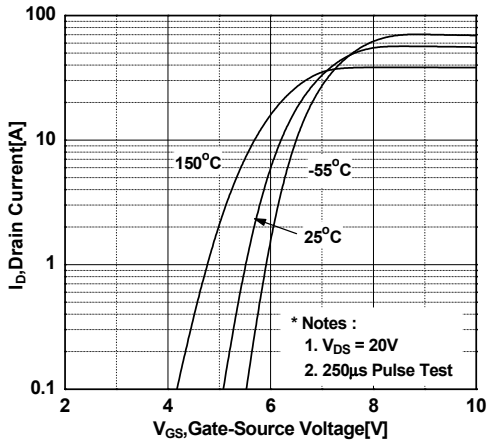


Figure 3. On-Resistance Variation vs. Drain Current and Gate Voltage

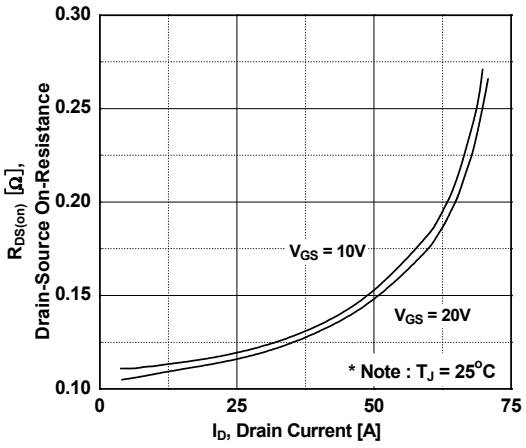


Figure 4. Body Diode Forward Voltage Variation vs. Source Current and Temperature

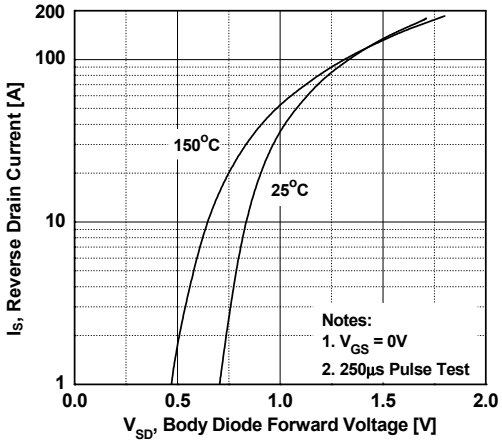


Figure 5. Capacitance Characteristics

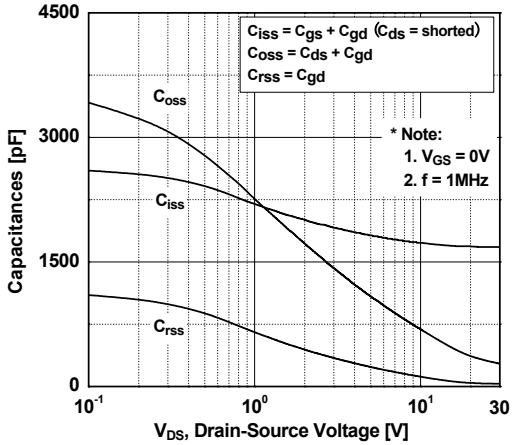
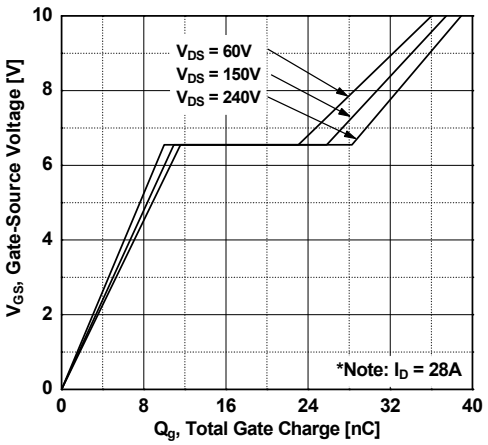


Figure 6. Gate Charge Characteristics



Typical Performance Characteristics (Continued)

Figure 7. Breakdown Voltage Variation vs. Temperature

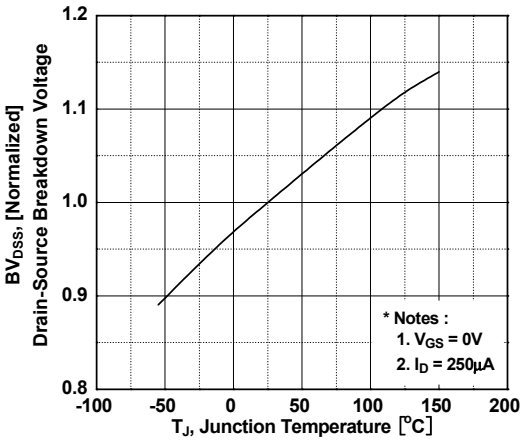


Figure 8. On-Resistance Variation vs. Temperature

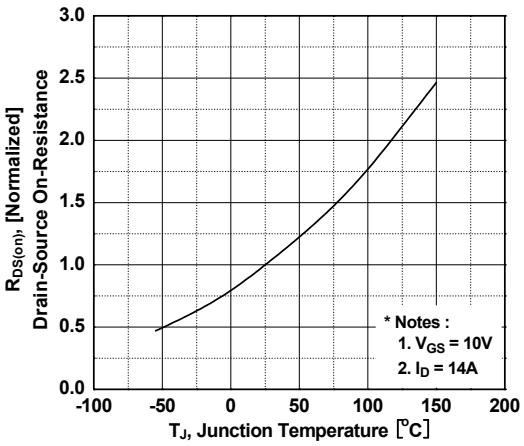


Figure 9. Maximum Safe Operating Area

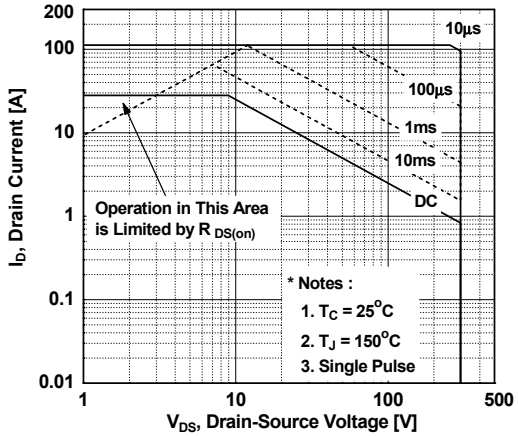


Figure 10. Maximum Drain Current vs. Case Temperature

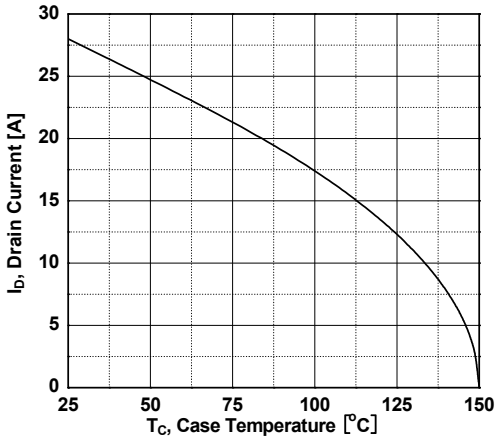
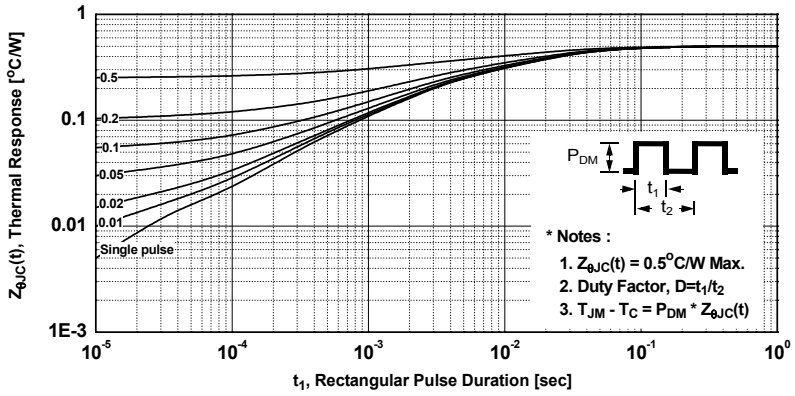


Figure 11. Transient Thermal Response Curve



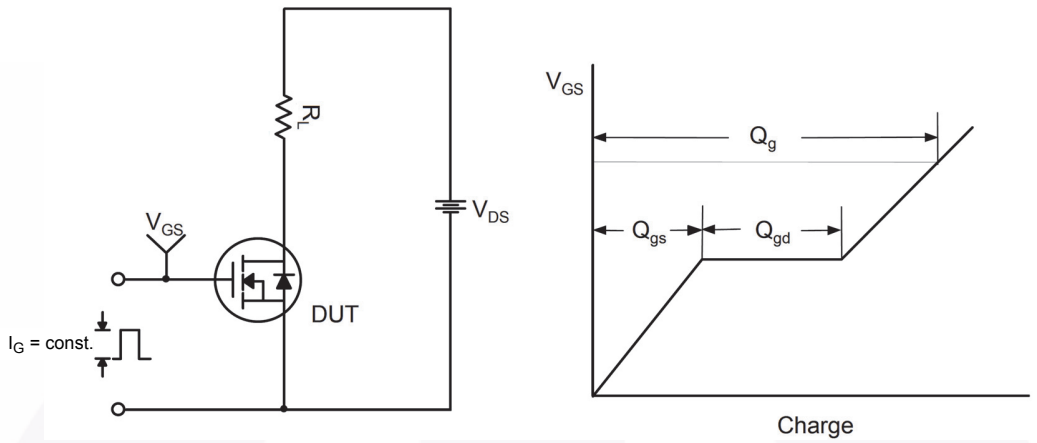


Figure 12. Gate Charge Test Circuit & Waveform

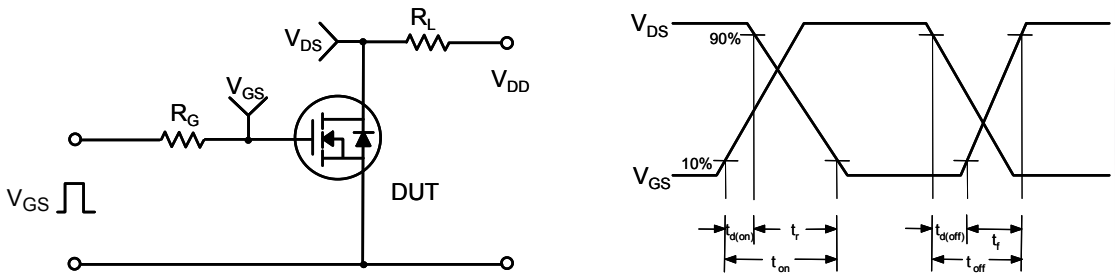


Figure 13. Resistive Switching Test Circuit & Waveforms

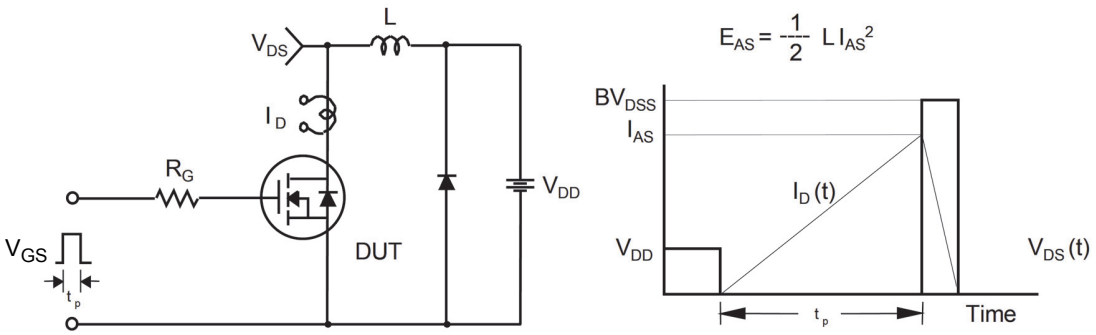


Figure 14. Unclamped Inductive Switching Test Circuit & Waveforms

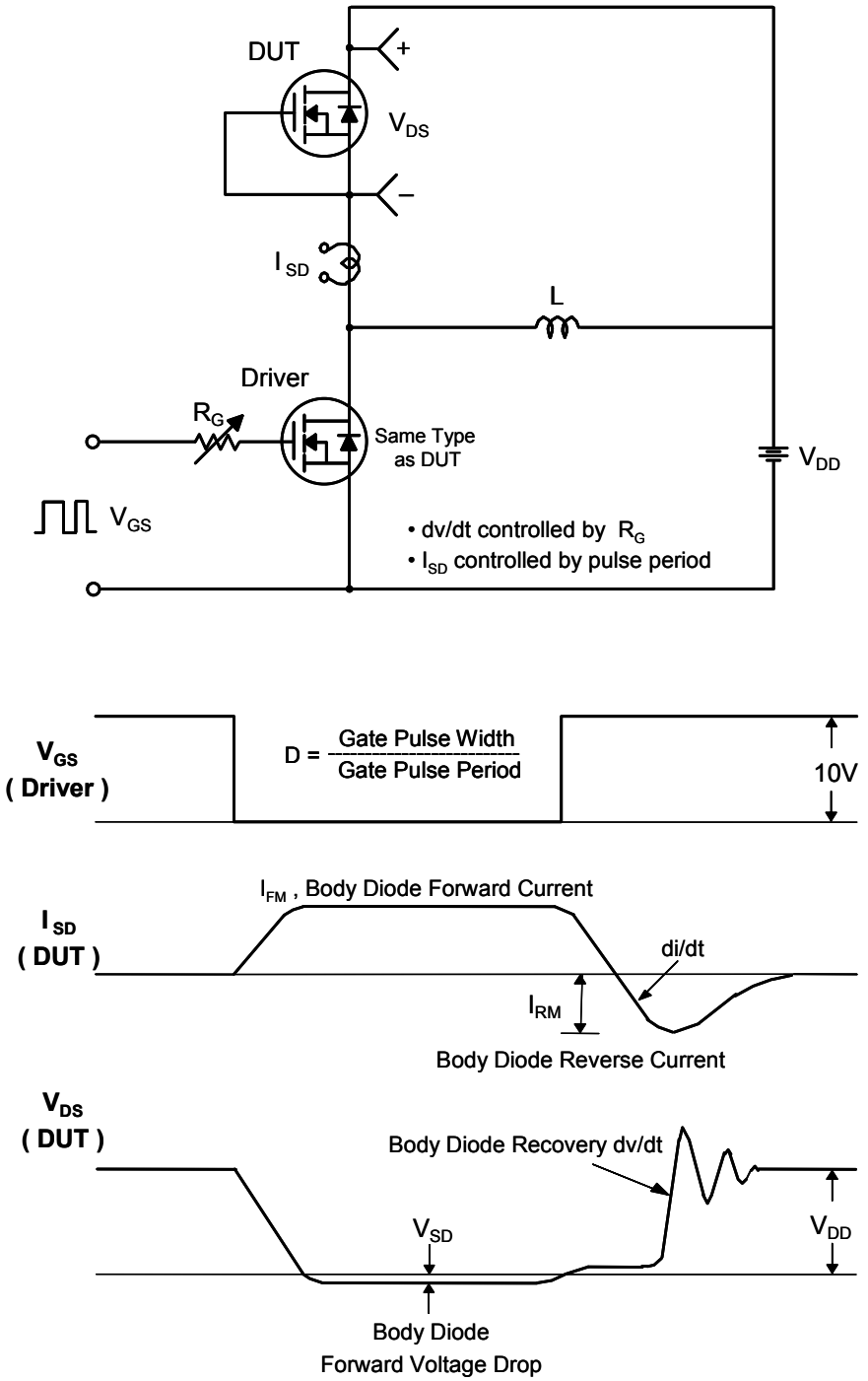


Figure 15. Peak Diode Recovery dv/dt Test Circuit & Waveforms

Mechanical Dimensions

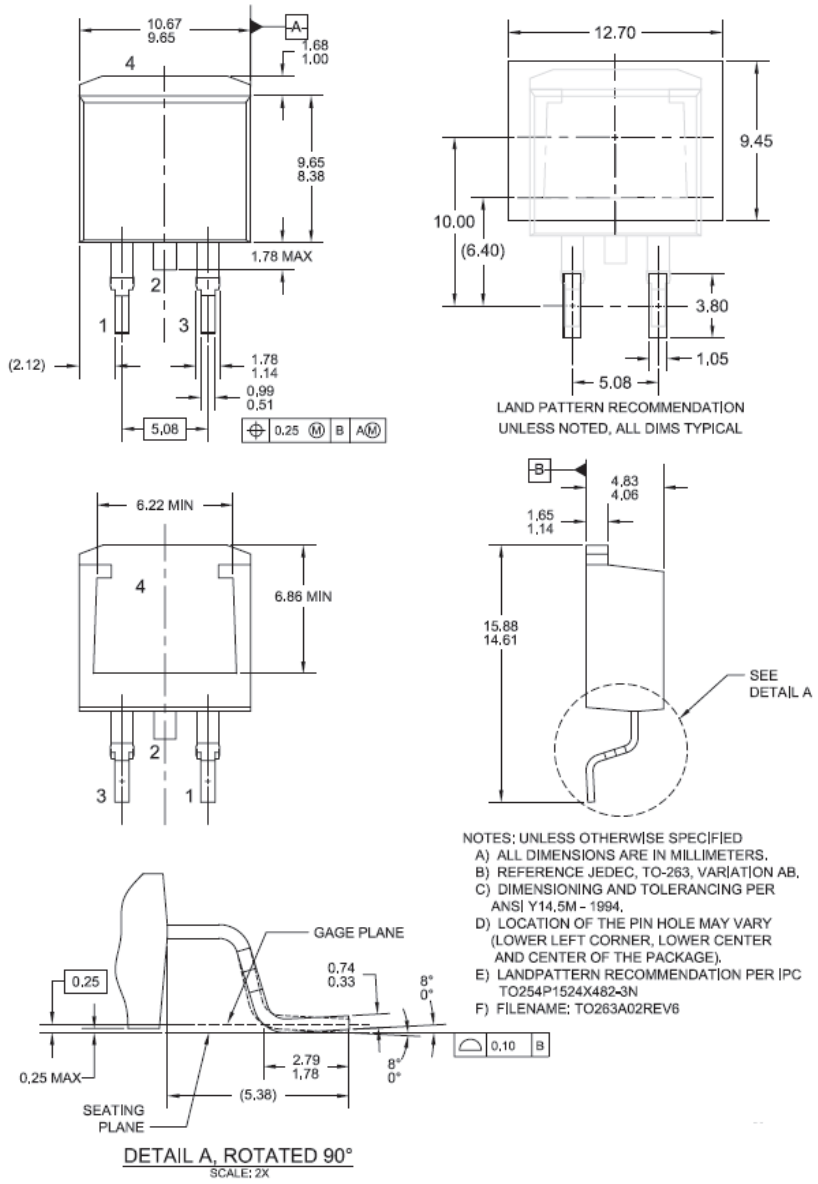


Figure 16. TO263 (D^2PAK), Molded, 2-Lead, Surface Mount

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